

NL27WZ14

Dual Schmitt-Trigger Inverter

The NL27WZ14 is a high performance dual inverter with Schmitt-Trigger inputs operating from a 1.65 to 5.5 V supply.

Pin configuration and function are the same as the NL27WZ04, but the inputs have hysteresis and, with its Schmitt trigger function, the NL27WZ14 can be used as a line receiver which will receive slow input signals. The NL27WZ14 is capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. In addition, it has a greater noise margin than conventional inverters. The NL27WZ14 has hysteresis between the positive-going and the negative-going input thresholds (typically 1 V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

Features

- Designed for 1.65 V to 5.5 V V_{CC} Operation
- Over Voltage Tolerant Inputs and Outputs
- LVTTTL Compatible – Interface Capability with 5 V TTL Logic with $V_{CC} = 3 V$
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Current Drive Capability is 24 mA at the Outputs
- Chip Complexity: FET = 72
- Pb-Free Packages are Available

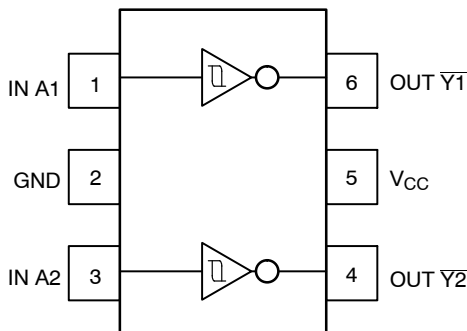


Figure 1. Pinout (Top View)

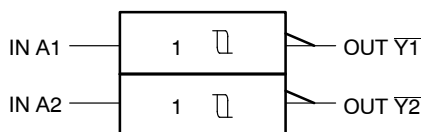
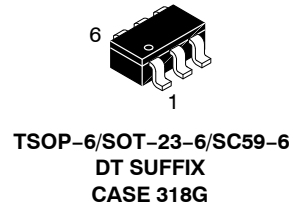
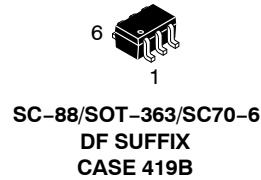


Figure 2. Logic Symbol



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MARKING DIAGRAMS



MA = Device Marking
M = Date Code*
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

PIN ASSIGNMENT

Pin	Function
1	IN A1
2	GND
3	IN A2
4	OUT Y2
5	V_{CC}
6	OUT Y1

FUNCTION TABLE

A Input	Y Output
L	H
H	L

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

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MAXIMUM RATINGS

Symbol	Characteristics	Value	Unit
V _{CC}	DC Supply Voltage	- 0.5 to +7.0	V
V _I	DC Input Voltage	- 0.5 ≤ V _I ≤ +7.0	V
V _O	DC Output Voltage Output in Z or LOW State (Note 1)	- 0.5 ≤ V _O ≤ 7.0	V
I _{IK}	DC Input Diode Current V _I < GND	- 50	mA
I _{OK}	DC Output Diode Current V _O < GND	- 50	mA
I _O	DC Output Sink Current	± 50	mA
I _{CC}	DC Supply Current per Supply Pin	± 100	mA
I _{GND}	DC Ground Current per Ground Pin	± 100	mA
T _{STG}	Storage Temperature Range	- 65 to + 150	°C
P _D	Power Dissipation in Still Air SC-88, TSOP-6	200	mW
θ _{JA}	Thermal Resistance SC-88, TSOP-6	333	°C/W
T _L	Lead Temperature, 1 mm from case for 10 s	260	°C
T _J	Junction Temperature under Bias	+ 150	°C
V _{ESD}	ESD Withstand Voltage Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 > 200 N/A	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. I_O absolute maximum rating must be observed.
2. Tested to EIA/JESD22-A114-A
3. Tested to EIA/JESD22-A115-A
4. Tested to JESD22-C101-A

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	Supply Voltage Operating Data Retention Only	1.65 1.5	5.5 5.5	V
V _I	Input Voltage	0	5.5	V
V _O	Output Voltage (High or LOW State)	0	5.5	V
T _A	Operating Free-Air Temperature	- 55	+ 125	°C
Δt/ΔV	Input Transition Rise or Fall Rate V _{CC} = 2.5 V ± 0.2 V V _{CC} = 3.0 V ± 0.3 V V _{CC} = 5.0 V ± 0.5 V	0 0 0	No Limit No Limit No Limit	ns/V

ORDERING INFORMATION

Device	Package	Shipping [†]
NL27WZ14DFT2	SC-88/SOT-363/SC70-6	3000 / Tape & Reel
NL27WZ14DFT2G	SC-88/SOT-363/SC70-6 (Pb-Free)	
NL27WZ14DTT1	TSOP-6/SOT-23-6/SC59-6	
NL27WZ14DTT1G	TSOP-6/SOT-23-6/SC59-6 (Pb-Free)	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	V _{CC} (V)	T _A = 25°C			-40°C ≤ T _A ≤ 85°C		-55°C ≤ T _A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
V _{T+}	Positive Input Threshold Voltage		2.3	1.0	1.5	1.8	1.0	1.8	1.0	1.8	V
			2.7	1.2	1.7	2.0	1.2	2.0	1.2	2.0	
			3.0	1.3	1.9	2.2	1.3	2.2	1.3	2.2	
			4.5	1.9	2.7	3.1	1.9	3.1	1.9	3.1	
			5.5	2.2	3.3	3.6	2.2	3.6	2.2	3.6	
V _{T-}	Negative Input Threshold Voltage		2.3	0.4	0.75	1.15	0.4	1.15	0.4	1.15	V
			2.7	0.5	0.87	1.4	0.5	1.4	0.5	1.4	
			3.0	0.6	1.0	1.5	0.6	1.5	0.6	1.5	
			4.5	1.0	1.5	2.0	1.0	2.0	1.0	2.0	
			5.5	1.2	1.9	2.3	1.2	2.3	1.2	2.3	
V _H	Input Hysteresis Voltage		2.3	0.25	0.75	1.1	0.25	1.1	0.25	1.1	V
			2.7	0.3	0.83	1.15	0.3	1.15	0.3	1.15	
			3.0	0.4	0.93	1.2	0.4	1.2	0.4	1.2	
			4.5	0.6	1.2	1.5	0.6	1.5	0.6	1.5	
			5.5	0.7	1.4	1.7	0.7	1.7	0.7	1.7	
V _{OH}	High-Level Output Voltage V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.65 to 5.5	V _{CC} - 0.1	V _{CC}		V _{CC} - 0.1		V _{CC} - 0.1		V
		I _{OH} = -3 mA	1.65	1.29	1.52		1.29		1.29		
		I _{OH} = -8 mA	2.3	1.9	2.1		1.9		1.8		
		I _{OH} = -12 mA	2.7	2.2	2.4		2.2		2.1		
		I _{OH} = -16 mA	3.0	2.4	2.7		2.4		2.3		
		I _{OH} = -24 mA	3.0	2.3	2.5		2.3		2.2		
		I _{OH} = -32 mA	4.5	3.8	4.0		3.8		3.7		
V _{OL}	Low-Level Output Voltage V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.65 to 5.5			0.1		0.1		0.1	V
		I _{OL} = 4 mA	1.65		0.08	0.24		0.24		0.24	
		I _{OL} = 8 mA	2.3		0.2	0.3		0.3		0.4	
		I _{OL} = 12 mA	2.7		0.22	0.4		0.4		0.5	
		I _{OL} = 16 mA	3.0		0.28	0.4		0.4		0.5	
		I _{OL} = 24 mA	3.0		0.38	0.55		0.55		0.55	
		I _{OL} = 32 mA	4.5		0.42	0.55		0.55		0.65	
I _{IN}	Input Leakage Current	V _{IN} = V _{CC} or GND	0 to 5.5			±0.1		±1.0		±1.0	μA
I _{OFF}	Power Off-Output Leakage Current	V _{OUT} = 5.5 V	0			1		10		10	μA
I _{CC}	Quiescent Supply Current	V _{IN} = V _{CC} or GND	5.5			1		10		10	μA

AC ELECTRICAL CHARACTERISTICS (Input t_r = t_f = 3.0 ns)

Symbol	Parameter	Condition	V _{CC} (V)	T _A = 25°C			-40°C ≤ T _A ≤ 85°C		-55°C ≤ T _A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t _{PLH} t _{PHL}	Propagation Delay Input A to Y (Figure 3 and 4)	R _L = 1 MΩ, C _L = 15 pF	2.5 ± 0.2	1.8	4.3	7.4	1.8	8.1	1.8	9.1	ns
		R _L = 1 MΩ, C _L = 15 pF	3.3 ± 0.3	1.5	3.3	5.0	1.5	5.5	1.5	6.5	
		R _L = 500 Ω, C _L = 50 pF		1.8	4.0	6.0	1.8	6.6	1.8	7.6	
		R _L = 1 MΩ, C _L = 15 pF	5.0 ± 0.5	1.0	2.7	4.1	1.0	4.5	1.0	5.5	
R _L = 500 Ω, C _L = 50 pF	1.2	3.2		4.9	1.2	5.4	1.2	6.4			

CAPACITIVE CHARACTERISTICS

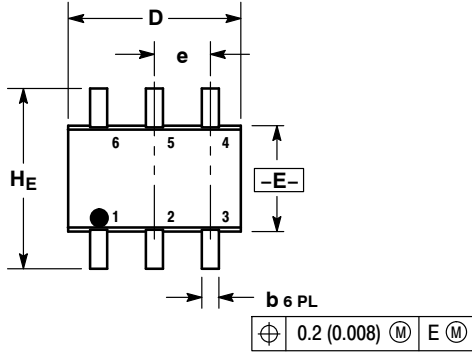
Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	V _{CC} = 5.5 V, V _I = 0 V or V _{CC}	2.5	pF
C _{PD}	Power Dissipation Capacitance (Note 5)	10 MHz, V _{CC} = 3.3 V, V _I = 0 V or V _{CC} 10 MHz, V _{CC} = 5.0 V, V _I = 0 V or V _{CC}	11 12.5	pF

5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

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PACKAGE DIMENSIONS

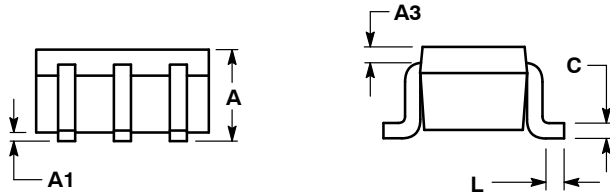
SC-88/SC70-6/SOT-363
CASE 419B-02
ISSUE W



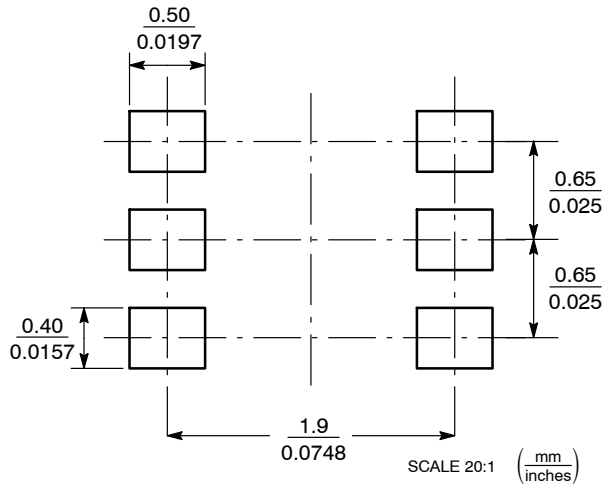
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.95	1.10	0.031	0.037	0.043
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.20 REF			0.008 REF		
b	0.10	0.21	0.30	0.004	0.008	0.012
C	0.10	0.14	0.25	0.004	0.005	0.010
D	1.80	2.00	2.20	0.070	0.078	0.086
E	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65 BSC			0.026 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	2.00	2.10	2.20	0.078	0.082	0.086



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.